

MS2200 Information

Heisener.com

Part Number MS2200

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - RF

Description TRANS RF BIPO 1167W 43.2A MS102

Package M102

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









MS2200 Specifications

Manufacturer Part Number	MS2200
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	M102
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	65V
Frequency - Transition	400MHz ~ 500MHz
Noise Figure (dB Typ @ f)	-
Gain	9.7dB
Power - Max	1167W
DC Current Gain (hFE) (Min) @ Ic, Vce	20 @ 5A, 5V
Current - Collector (Ic) (Max)	43.2A
Operating Temperature	200°C (TJ)
Mounting Type	Chassis Mount
Package / Case	M102
Supplier Device Package	M102
	Report errors?

MS2200 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

MS2200 Payment Methods





















MS2200 Shipping Methods













If you have any question about MS2200, please do not hesitate to contact us!

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